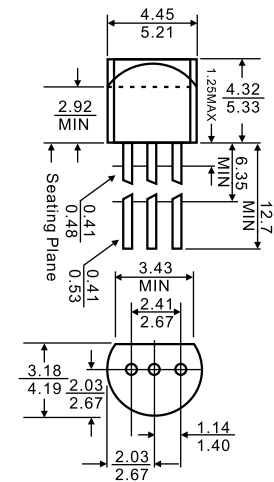




1. EMITTER
2. COLLECTOR
3. BASE

TO-92



Dimensions in inches and (millimeters)

Features

- ✧ Excellent h_{FE} linearity

MAXIMUM RATINGS ($T_A=25^\circ\text{C}$ unless otherwise noted)

Symbol	Parameter	Value	Units
V_{CBO}	Collector-Base Voltage	35	V
V_{CEO}	Collector-Emitter Voltage	30	V
V_{EBO}	Emitter-Base Voltage	5	V
I_C	Collector Current –Continuous	0.5	A
P_C	Collector Power Dissipation	500	mW
T_J	Junction Temperature	150	$^\circ\text{C}$
T_{stg}	Storage Temperature	-55-150	$^\circ\text{C}$

ELECTRICAL CHARACTERISTICS ($T_{amb}=25^\circ\text{C}$ unless otherwise specified)

Parameter	Symbol	Test conditions	MIN	TYP	MAX	UNIT
Collector-base breakdown voltage	$V(BR)_{CBO}$	$I_C = 100\mu\text{A}$, $I_E = 0$	35			V
Collector-emitter breakdown voltage	$V(BR)_{CEO}$	$I_C = 1\text{mA}$, $I_B = 0$	30			V
Emitter-base breakdown voltage	$V(BR)_{EBO}$	$I_E = 100\mu\text{A}$, $I_C = 0$	5			V
Collector cut-off current	I_{CBO}	$V_{CB} = 35\text{V}$, $I_E = 0$			0.1	μA
Emitter cut-off current	I_{EBO}	$V_{EB} = 5\text{V}$, $I_C = 0$			0.1	μA
DC current gain	$h_{FE(1)}$	$V_{CE} = 1\text{V}$, $I_C = 100\text{mA}$	70		400	
	$h_{FE(2)}$	$V_{CE} = 6\text{V}$, $I_C = 400\text{mA}$	25			
Collector-emitter saturation voltage	$V_{CE(sat)}$	$I_C = 100\text{mA}$, $I_B = 10\text{mA}$			0.25	V
Base-emitter voltage	V_{BE}	$V_{CE} = 1\text{V}$, $I_C = 100\text{mA}$			1.0	V
Transition frequency	f_T	$V_{CE} = 12\text{V}$, $I_C = 2\text{mA}$		300		MHz
Collector output capacitance	C_{ob}	$V_{CB} = 6\text{V}$, $I_E = 0$, $f = 1\text{MHz}$		7		pF

CLASSIFICATION OF h_{FE}

Rank		O	Y	GR
Range	$h_{FE(1)}$	70-140	120-240	200-400
	$h_{FE(2)}$	25(min)	40(min)	

Typical Characteristics

